

## **INCHANGE SEMICONDUCTOR**

## isc N-Channel Mosfet Transistor

## 50N15

### • FEATURES

- Drain Current –I\_D= 12A@ T\_C=25 $^\circ\!\!\mathrm{C}$
- Drain Source Voltage-: V<sub>DSS</sub>= 150V (Min)
- Static Drain-Source On-Resistance : R<sub>DS(on)</sub> <23m Ω
- Avalanche Energy Specified
- · Fast Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

• Designed for in a wide variety of applocations.

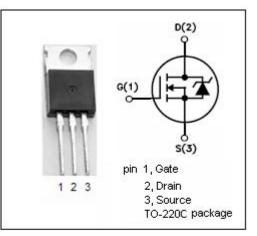
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

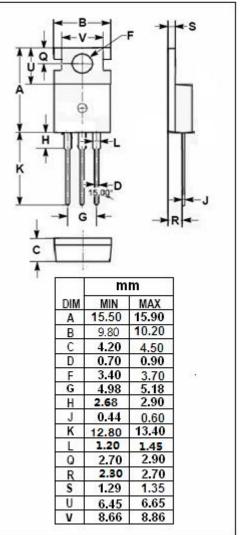
SYMBOL	PARAMETER VALUE		UNIT
V <sub>DSS</sub>	Drain-Source Voltage	150	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±20	V
ID	Drain Current-Continuous 50		А
I <sub>DM</sub>	Drain Current-Single Plused	210	А
Ptot	Total Dissipation@TC=25°C	220	W
Tj	Max. Operating Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~175	°C

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.68	°C/W
R <sub>th j-a</sub>	Thermal Resistance, Junction to Ambient	62.5	°C/W

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### **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	150		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ = 0.25mA	2.5	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =40A		23	mΩ
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V; V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0		1	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 40A; V <sub>GS</sub> = 0		1.2	V

## **NOTICE:**

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